NSN 5961-01-226-3733

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Demilitarization:

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-226-3733 **Inclosure Material:** Metal **Overall Length:** 0.150 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-52 **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 25.0 drain to gate voltage and 25.0 drain to source voltage and 4.0 gate to source voltage **Current Rating Per Characteristic:** 20.00 milliamperes gate current **Power Rating Per Characteristic:** 500.0 milliwatts total power dissipation **Test Data Document:** 80249-912534 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**